

Temperature and Radiation Tolerance Studies of CdSe/CdTe Bilayer Solar cells on Space-Qualified Coverglass

Aesha P. Patel, Adam B. Phillips, Ebin Bastola, Nadeesha Katakumbura, Zachary Zawisza, Robert Snuggs, Manoj K. Jamarkattel, Abasi Abudulimu, Richard Irving, Michael J. Heben, Randy J. Ellingson

Wright Center for Photovoltaics Innovation and Commercialization (PVIC), Department of Physics and Astronomy
University of Toledo, Ohio, 43606, USA



THE UNIVERSITY OF
TOLEDO
1872



Motivation and Background

- II-VI thin film solar cells are expected to show superior high energy radiation tolerance and achieve higher specific power with lower manufacturing costs than Si or III-V solar cells [1]
- Highest recorded efficiency for CdS/CdTe solar cell on flexible and ultra-thin glass superstrate has been 16.4% [2]
- Replacing CdS with CdSe significantly improves current collection at lower wavelength region in visible spectrum [3]
- Incorporation of novel Indium Gallium Oxide (IGO) as an emitter in CdSe/CdTe solar cell improves device efficiency under AM1.5G condition [4]
- Here, we demonstrate fabrication of CdSe/CdTe bilayer solar cell directly onto space coverglass and report preliminary results of thermal cycling and proton radiation tolerance on a 15% efficient CdSe/CdTe device

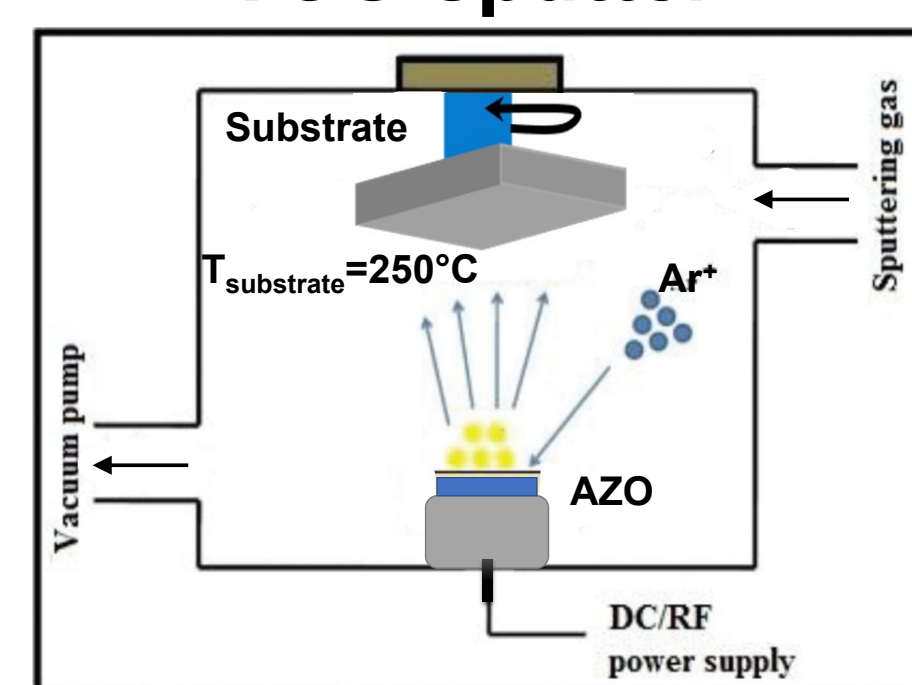
Methodology

Device fabrication

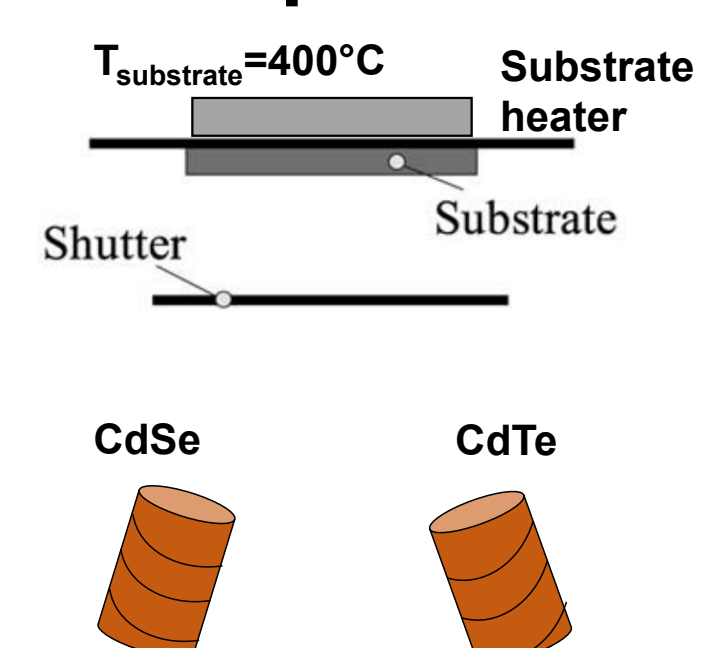
Glass cleaning

Corning
0214
(0.75% Ce-
doped
borosilicate)

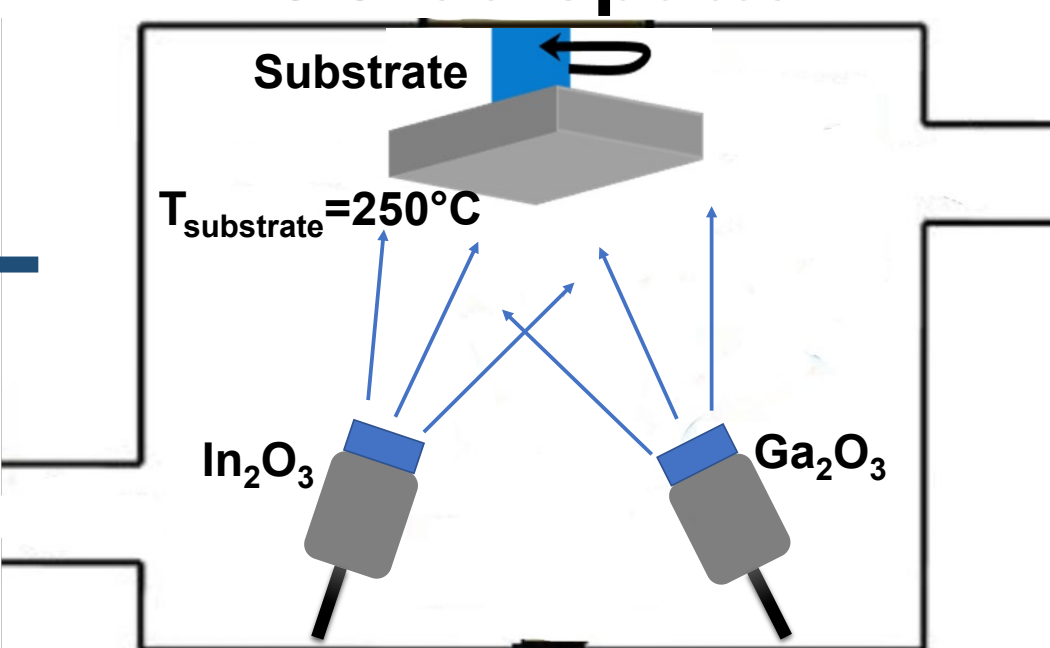
TCO sputter



CdSe/CdTe multisource evaporation



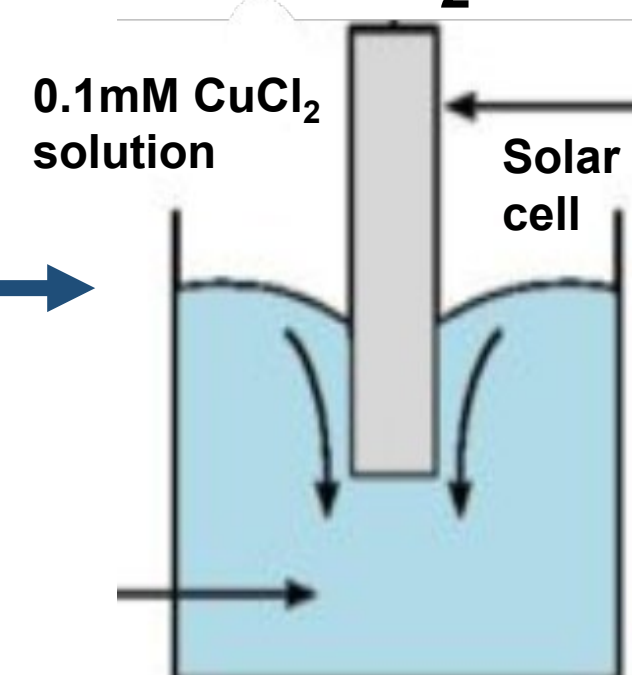
IGO co-sputter



CdCl₂ treatment

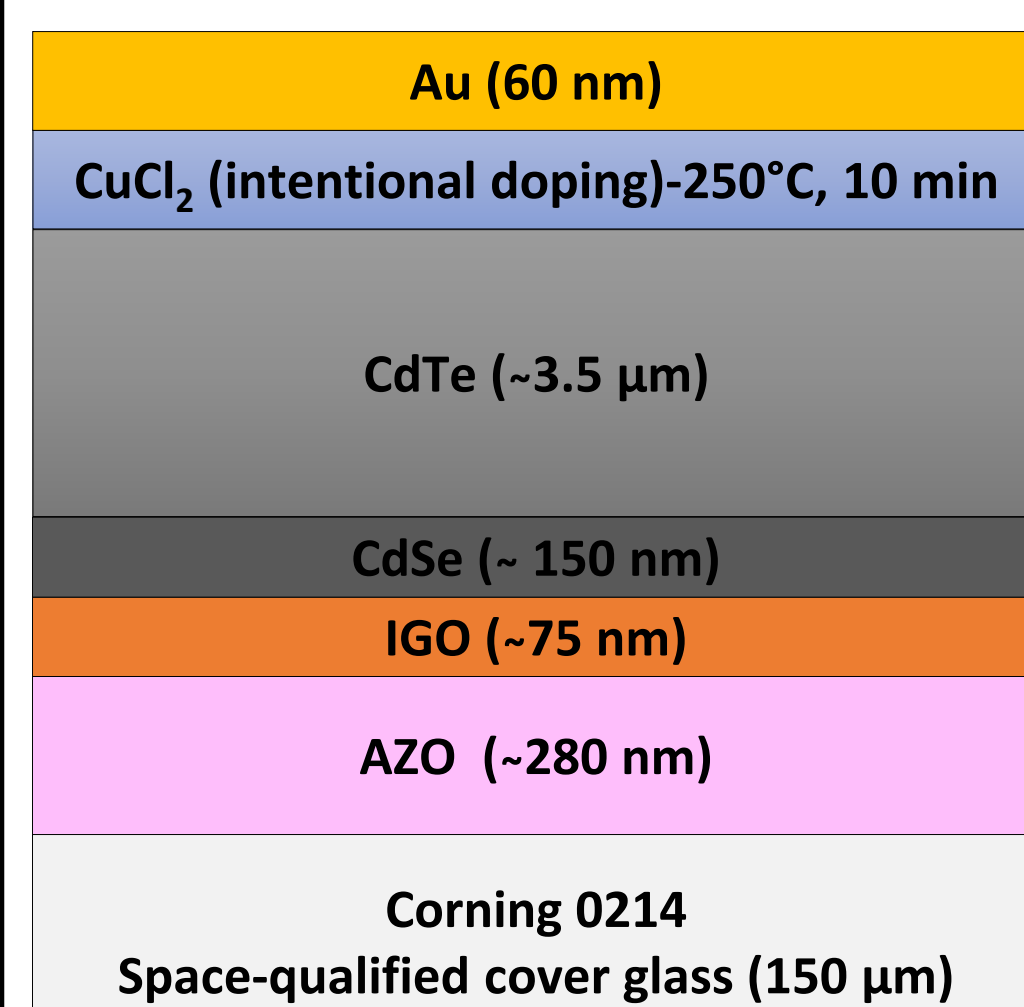
- Solution: CdCl₂ + CH₃OH saturated solution
- Conditions: 400°C for 30 min in N₂ environment
- Purpose: Grain boundary passivation, grain growth

CuCl₂ treatment

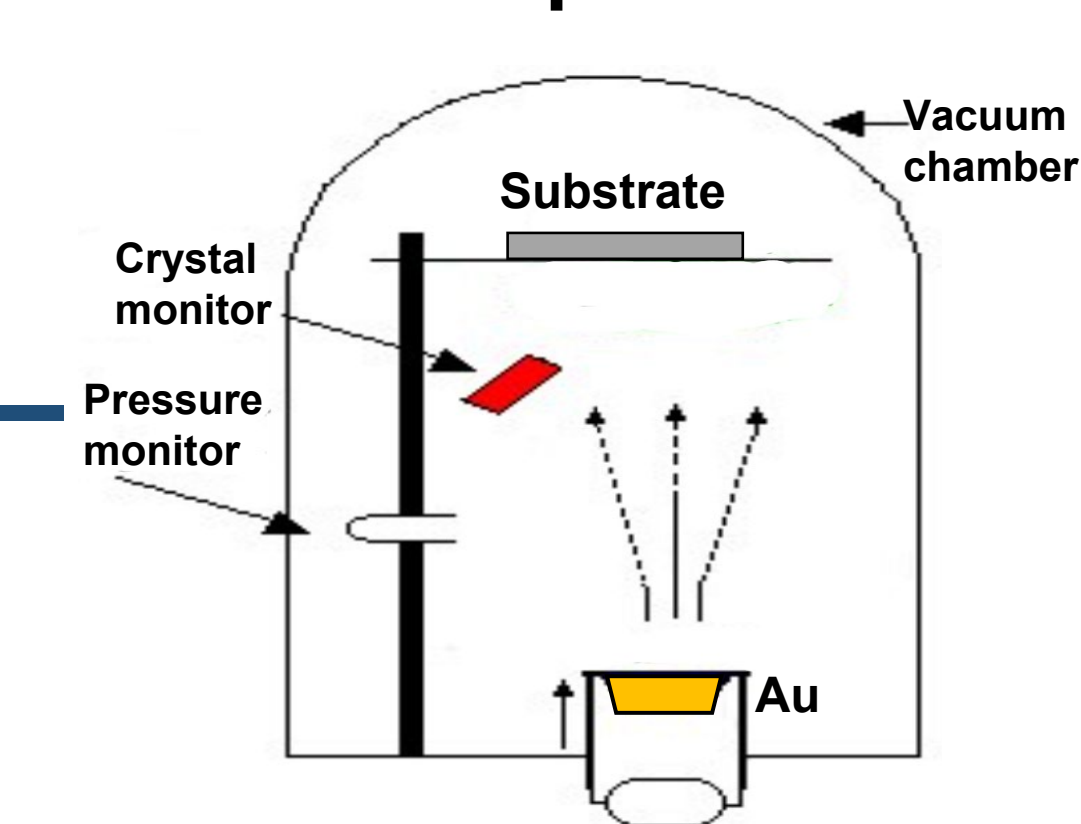


- Heat treatment: 250°C for 10 min in hot oven
- Purpose: p-type Cu doping

Schematic diagram of CdSe/CdTe solar cell



Au evaporation



Results and Discussion

Device Performance

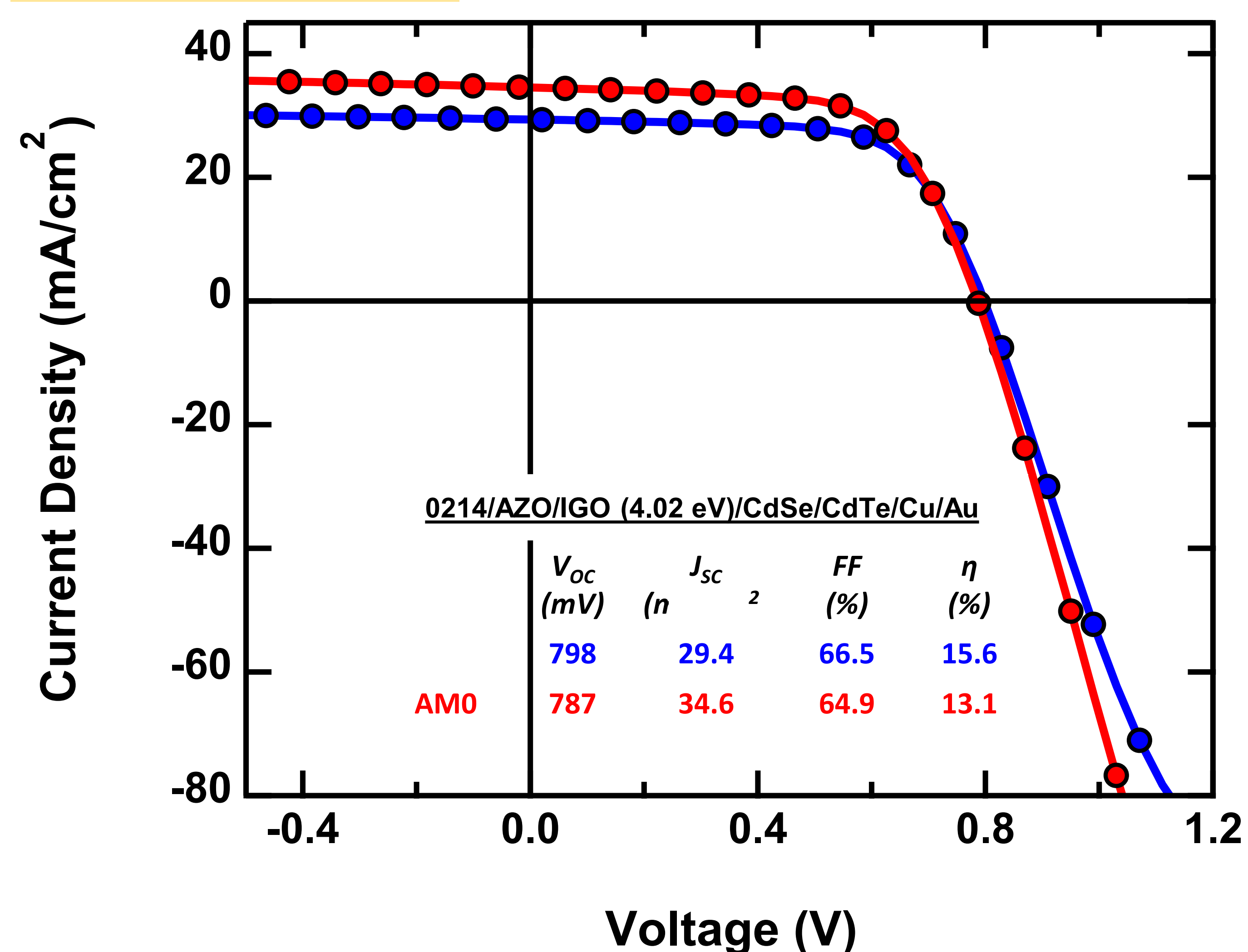


Fig. 1: Current density (J)-voltage (V) curves for AM1.5G and AM0 conditions

Thermal Cycling: -20°C to 80°C under AM1.5G

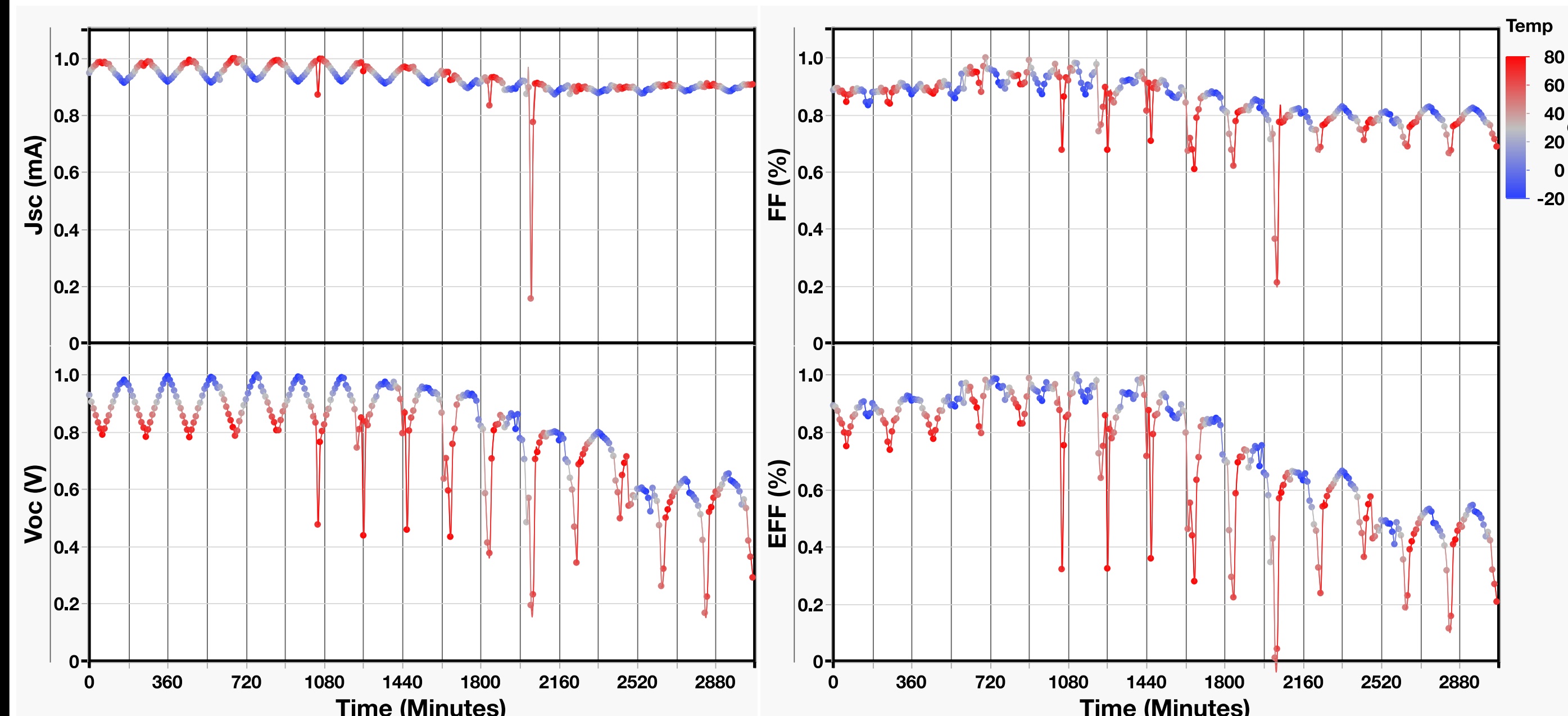


Fig. 2: Thermal cycling from -20°C to 80°C under AM1.5G

➤ ~16 cycles were performed over +3000 minutes

➤ Within first few cycles, no degradation observed in J_{SC} and V_{OC}

Proton Radiation (film-side): ~50-240 keV, low & high fluence

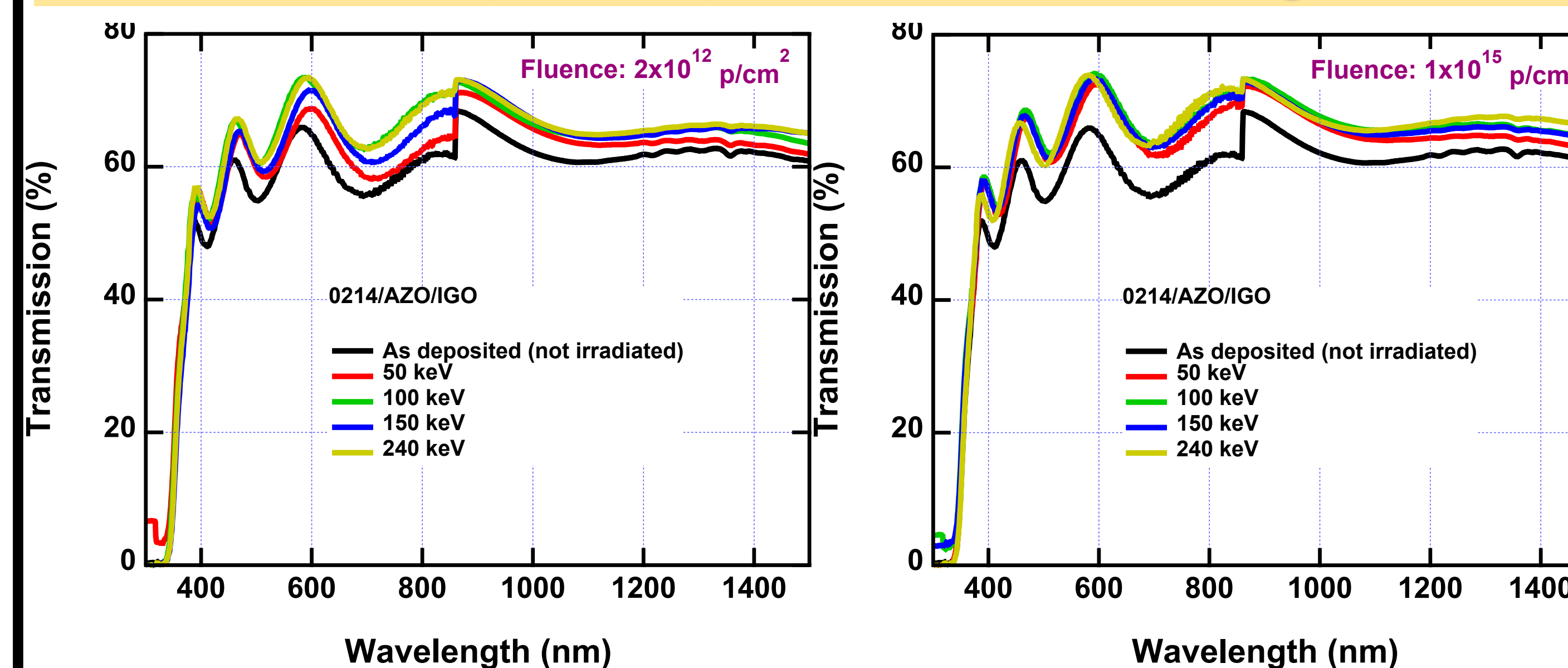


Fig. 3: T(%) measurements for pre- and post-proton irradiated AZO/IGO films on space coverglass for low (2×10^{12}) and high (1×10^{15}) p/cm² fluences

➤ Films irradiated from film-side (no encapsulation). Higher T(%) for all irradiated samples. Minor increment in transmission with increase in energy

Conclusion

- Highest achieved device efficiency for multisource evaporated CdSe/CdTe bilayer solar cells, deposited directly onto 150 μ m space coverglass is 15.6% and 13.1% under AM1.5G and AM0 conditions, respectively
- From thermal cycling results under AM1.5G, higher fluctuations observed in fill factor (FF) and V_{OC} , thereby lowering efficiency post 8-10 cycles
- Film-side proton irradiated 0214/AZO/IGO films showed higher transmission (%) than film that did not undergo irradiation
- Transmission(%) increased with increase in energy dosage and fluence

Next Steps

- Further experiments will be conducted to optimize IGO bandgap, CdCl₂ and CuCl₂ treatment conditions to improve bilayer device efficiency
- Thermal cycling to understand degradation mechanisms of CdSe/CdTe solar cells under AM0 condition
- Au stability must be determined
- Looking to collaborate for electron and higher energy proton irradiation experiments

References

- [1] A. Romeo, D. L. Bätzner, W. Hajdas, H. Zogg, and A. N. Tiwari, "Potential of CdTe Thin Film Solar Cells for Space Application," *Proceedings of 17th European Photovoltaic Solar Energy Conference and Exhibition*, vol. 3, no. October, pp. 2183–2186, 2002
- [2] H. P. Mahabaduge *et al.*, "High-efficiency, flexible CdTe solar cells on ultra-thin glass substrates," *Applied Physics Letters*, vol. 106, no. 13, pp. 3–7, 2015, doi: 10.1063/1.4916634
- [3] E. Bastola *et al.*, "Understanding the Interplay between CdSe Thickness and Cu Doping Temperature in CdSe/CdTe Devices," 2021 IEEE 48th Photovoltaic Specialists Conference (PVSC), 2021, pp. 1421-1426, doi: 10.1109/PVSC43889.2021.9518832
- [4] M. K. Jamarkattel *et al.*, "Indium Gallium Oxide Emitters for High-Efficiency CdTe-Based Solar Cells," *ACS Applied Energy Materials*, 2022, doi: 10.1021/acsaem.2c00153

Acknowledgments

This material is based on research sponsored by Air Force Research Laboratory under agreement number FA9453-21-C-0056. The U.S. Government is authorized to reproduce and distribute reprints for Governmental purposes notwithstanding any copyright notation thereon. The views expressed are those of the authors and do not reflect the official guidance or position of the United States Government, the Department of Defense or the United States Air Force. The appearance of external hyperlinks does not constitute endorsement by the United States Department of Defense (DoD) of the linked websites, or the information, products, or services contained therein. The DoD does not exercise any editorial, security, or other control over the information you may find at these locations. Approved for public release; distribution is unlimited. Public Affairs release approval #AFRL-2023-0090.

To see other research at the Wright Center for Photovoltaics Innovation and Commercialization please visit our website at: <http://www.utoledo.edu/research/pvic/>

